



High-Energy Picosecond Laser

PICOPOWER™-RG1-1064-10K



he PICOPOWER™- RG1-1064-10K picosecond laser delivers ultrashort pulses with high energy, high peak and average power at 1064 nm wavelength with variable repetition rates from single shot to 10 kHz. It features a unique synchronization capability with unsurpassed 3.5 ps jitter for pulses on demand. Optional wavelengths at 532 nm, 355 nm and 266 nm are available collinearly or as multiple output beams. The distinctive features of this laser are excellent power, pulse-to-pulse and beam pointing stability, diffraction-limited output beam, pulse-on-demand triggering and peak power of more than 2 MW with less than 30 W electrical power consumption. It is an ideal choice for numerous applications, including micro-machining of metal and nonmetal materials, semiconductor wafer inspection, carving, nonlinear optics, ultrafast spectroscopy and many others.

Features

- Single or multiple outputs at 1064 nm, 532 nm, 355 nm or 266 nm wavelengths
- Unsurpassed **3.5 ps rms jitter** to external trigger
- · Less than **30 ps** pulse width
- **50 μJ** pulse energy at 1064 nm
- More than **2 MW** peak power at 1064 nm
- Internal and external trigger
- Air-cooled, compact and cost effective
- Excellent Gaussian TEM on beam profile
- Variable repetition rate

Applications

- High-speed and precision micro-machining (glass, silicon, plastics, etc.)
- Fluorescence lifetime measurements
- Multi-photon non-linear microscopy
- Marking, carving and 3D engraving
- Time-resolved spectroscopy
- Terahertz imaging
- Nonlinear optics



Technical Specifications:	Typical \	/alues			
OPTICAL and ELECTRICAL CHA	ARACTERIS	STICS			
Parameter	Unit	Fundamental Harmonics (optional)			
Wavelength	nm	1064	532	355	266
Pulse Energy, single shot to 5 kHz	μЈ	55	33	16	12
Pulse Energy @ 10 kHz	μЈ	50	29	13.5	10
Pulse Width, single shot to 10 kHz	ps	< 30	< 30	< 25	< 25
Peak Power, single shot to 5 kHz	MW	2.3	1.7	0.9	0.7
Peak Power @ 10 kHz	MW	2.1	1.4	0.8	0.6
Average Power @ 10 kHz	mW	500	290	135	100
Long Term Power Stability (8 hrs)	%, rms	< 1.0	< 2.0	< 3.0	< 4.0
Pulse-to-Pulse Energy Stability	%, rms	< 1.0	< 2.0	< 3.0	< 4.0
Beam Diameter, 1/e ²	mm	1.4	1.4 Available on request		
Polarization (linear)	%	> 99.5	> 99.9	> 99.9	> 99.9
Beam Divergence	mrad	< 1.2	< 2.0	< 3.0	< 3.0
Beam Pointing Stability (rms)	μrad	< 30	< 30	< 30	< 30
Pre-Pulse Contrast Ratio 1)		> 10³ : 1	> 10 ⁵ : 1	> 10 ⁷ : 1	> 109: 1
Post-Pulse Contrast Ratio 1)		> 10 ² :1	> 10³: 1	> 10 ⁵ : 1	> 10 ⁷ : 1
Spatial Mode / M ²		$TEM_{00} / M^2 < 1.2$ $TEM_{00} / M^2 < 1.5$			
Repetition Rate	kHz	Single shot to 10 kHz			
Internal Trigger Repetition Rate	kHz	0.1 10			
External Trigger Repetition Rate	kHz	Single shot to 10 kHz			
External Trigger Specifications		TTL (4.5 5.5 V on 50 Ω load)			
		Rising edge: < 10 ns; Pulse width: min. 250 ns, max. 1.3			
Delay of Laser Pulse to TRIG IN	ns	~ 500			
Optical SYNC OUT Pulse	ps	Optional, jitter < 1 ps, rise time < 50 ps			
Electrical SYNC OUT Pulse		+5 V on 50 Ω load			
Jitter of Laser Pulse to External	ps, rms	3.5			
Trigger		Adjustable from 100 to 11000			
Delay SYNC OUT to Laser Pulse	ns	Adjustable from -100 to +1000 50			
Jitter of Electrical SYNC OUT Pulse MECHANICAL CHARACTERIST	ps		50)	
MECHANICAL CHARACTERIST	ics	Dimer	nsions	Wei	aht
Laser Head	165 x 95			10 kg	
Laser Diode Driver		130 x 65 x 105 mm ³		1 kg	
Control Unit		105 x 65 x 105 mm ³		1 kg	
GENERAL CHARACTERISTICS		103 7 03 7		1	·9
Power Requirements		+12 V DC	C, 5 A or 100 240	VAC with AC/DC	adapter
Power Consumption			< 30		•
Operating Temperature Range		15°C − 35°C			
Cooling		Passive (convection)			
Typical warm-up time			< 15	•	

Note: 1) Peak-to-peak with respect to residual pulses.

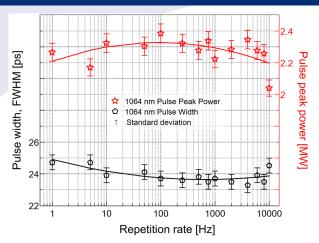


Min. 93 mm, max. 103 mm, adjustable

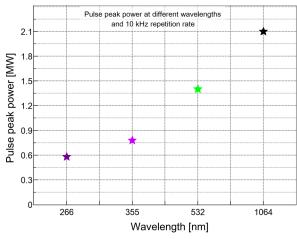
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Beam height

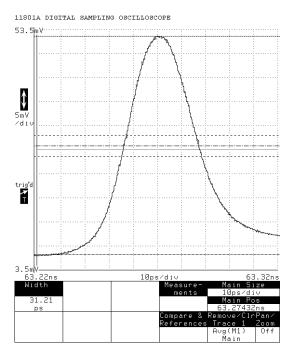
Performance of PICOPOWER™-RG1-1064-10K: Typical Values



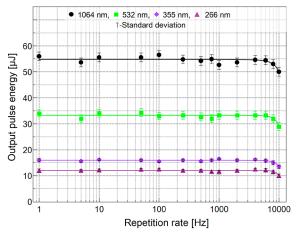
Pulse width and peak power at different repetition rates for 1064 nm wavelength.



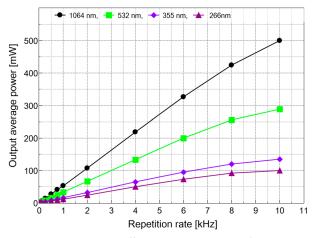
Peak power at 1064 nm and its harmonic wavelengths at 10 kHz repetition rate.



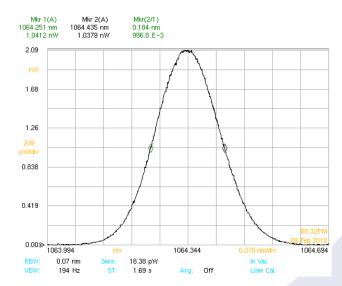
Pulse width at 1064 nm wavelength before deconvolution measured with 30 GHz photodetector.



Pulse energy at different repetition rates for 1064, 532, 355 and 266 nm wavelengths.



Average power at different repetition rates for 1064, 532, 355 and 266 nm wavelengths.

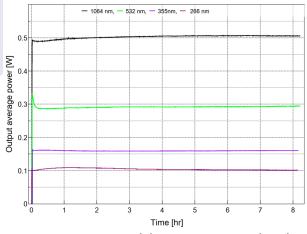


Spectral bandwidth at 1064 nm wavelength.



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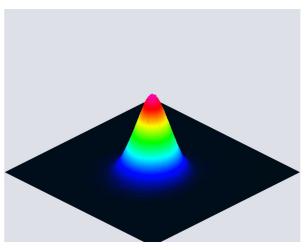
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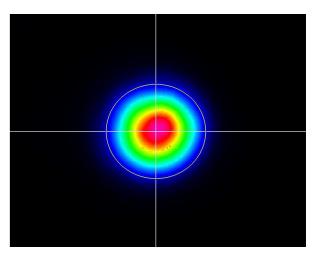


Long-term power stability at 1064 nm wavelength.

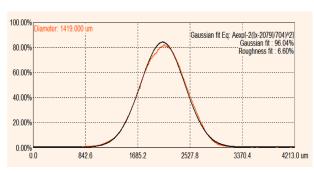


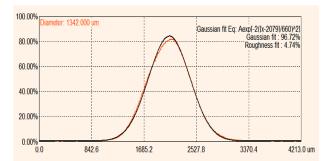
Beam pointing stability at 10 kHz repetition rate.



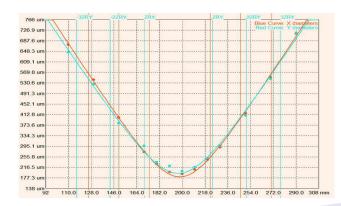


3D and 2D far-field beam profile measured at 540 mm distance from laser head for 1064 nm wavelength.





1D cross section and Gaussian fit showing nearly 95% overlap.



Beam quality measured at maximum output power according to ISO 11146 standard (\pm 5%).

 $M_{eff}^2 = 1.02$

 $Div_{eff} = 0.93 \text{ mrad}$

 $BPP_{eff} = 0.34 \text{ mrad*mm}$

 $z0_{eff} = 1551 \text{ mm}$

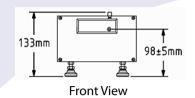


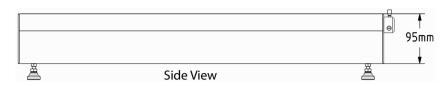
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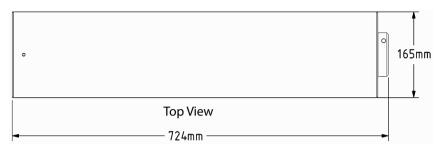


High-Energy Picosecond Laser: PICOPOWER™-RG1-1064-10K

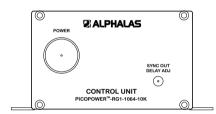
Outline Drawings of PICOPOWER™-RG1-1064-10K



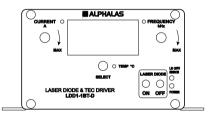




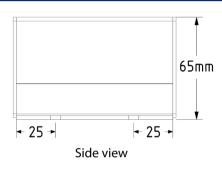
Outline Drawings of PICOPOWER™ Laser Diode Driver and Control Unit

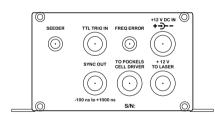


Control Unit Front View

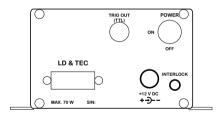


Laser Diode Driver Front View

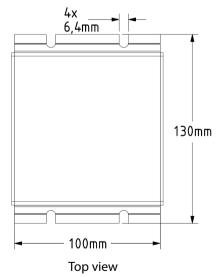




Control Unit Back View



Laser Diode Driver Back View





DANGER – VISIBLE AND INVISIBLE LASER RADIATION AVOID EYE OR SKIN EXPOSURE TO DIRECT OR SCATTERED RADIATION CLASS 4 LASER PRODUCT IEC / EN 60825-1

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